MOSFETs Silicon N-Channel MOS (π-MOSVII)

# TK5A45DA

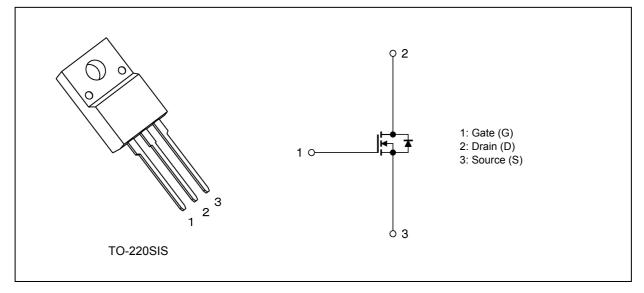
#### 1. Applications

Switching Voltage Regulators

#### 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 1.52 \Omega$  (typ.)
- (2) High forward transfer admittance:  $|Y_{fs}| = 1.5 \text{ S}$  (typ.)
- (3) Low leakage current:  $I_{DSS} = 10 \ \mu A \ (max) \ (V_{DS} = 450 \ V)$
- (4) Enhancement mode:  $V_{th}$  = 2.4 to 4.4 V ( $V_{DS}$  = 10 V,  $I_D$  = 1 mA)

#### 3. Packaging and Internal Circuit



### 4. Absolute Maximum Ratings (Note) ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics			Rating	Unit	
Drain-source voltage		V <sub>DSS</sub>	450	V	
Gate-source voltage		V <sub>GSS</sub>	±30		
Drain current (DC)	(Note 1)	Ι <sub>D</sub>	4.5	Α	
Drain current (pulsed)	(Note 1)	I <sub>DP</sub>	18	1	
Power dissipation $(T_c = 25^{\circ}C)$		PD	30	W	
Single-pulse avalanche energy	(Note 2)	E <sub>AS</sub>	122	mJ	
Avalanche current		I <sub>AR</sub>	4.5	A	
Repetitive avalanche energy	(Note 3)	E <sub>AR</sub>	3.0	mJ	
Channel temperature		T <sub>ch</sub>	150	°C	
Storage temperature		T <sub>stg</sub>	-55 to 150	]	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production 2009-11 2014-01-05 Rev.3.0

#### 5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R <sub>th(ch-c)</sub>	4.17	°C/W
Channel-to-ambient thermal resistance	R <sub>th(ch-a)</sub>	62.5	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V<sub>DD</sub> = 90 V, T<sub>ch</sub> = 25°C (initial), L = 10 mH, R<sub>G</sub> = 25  $\Omega$ , I<sub>AR</sub> = 4.5 A

Note 3: Repetitive rating; pulse width limited by maximum channel temperature

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

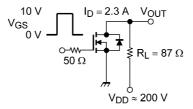
#### 6. Electrical Characteristics

#### 6.1. Static Characteristics (Ta = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±30 V, $V_{DS}$ = 0 V	_	_	±1	μA
Drain cut-off current	I <sub>DSS</sub>	V <sub>DS</sub> = 450 V, V <sub>GS</sub> = 0 V	_	_	10	
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	I <sub>D</sub> = 10 mA, V <sub>GS</sub> = 0 V	450	_	_	V
Gate threshold voltage	V <sub>th</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.4	—	4.4	
Drain-source on-resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 2.3 A	_	1.52	1.75	Ω
Forward transfer admittance	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 2.3 A	0.4	1.5		S

### 6.2. Dynamic Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	_	380	_	pF
Reverse transfer capacitance	C <sub>rss</sub>		_	2.5	_	
Output capacitance	C <sub>oss</sub>			45	_	
Switching time (rise time)	t <sub>r</sub>	See Figure 6.2.1.		18	_	ns
Switching time (turn-on time)	t <sub>on</sub>		_	40	_	
Switching time (fall time)	t <sub>f</sub>			7	_	
Switching time (turn-off time)	t <sub>off</sub>		_	55	_	



Duty  $\leq$  1%,  $t_W = 10~\mu s$ 

Fig. 6.2.1 Switching Time Test Circuit

#### 6.3. Gate Charge Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 360 \text{ V},  \text{V}_{GS} \text{ = } 10 \text{ V},  \text{I}_{D} \text{ = } 4.5 \text{ A}$	_	9	—	nC
Gate-source charge	Q <sub>gs</sub>	]	_	5	_	
Gate-drain charge	Q <sub>gd</sub>		_	4	_	

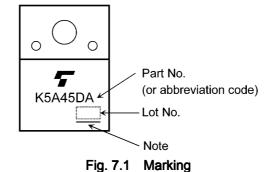
#### 6.4. Source-Drain Characteristics ( $T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (DC)	(Note 1)	I <sub>DR</sub>	—	_	_	4.5	A
Reverse drain current (pulsed)	(Note 1)	I <sub>DRP</sub>	—	_	—	18	
Diode forward voltage		V <sub>DSF</sub>	I <sub>DR1</sub> = 4.5 A, V <sub>GS</sub> = 0 V	—	_	-1.7	V
Reverse recovery time		t <sub>rr</sub>	I <sub>DR</sub> = 4.5 A, V <sub>GS</sub> = 0 V	_	1000	—	ns
Reverse recovery charge		Q <sub>rr</sub>	-dI <sub>DR</sub> /dt = 100 A/μs		5.5	_	nC

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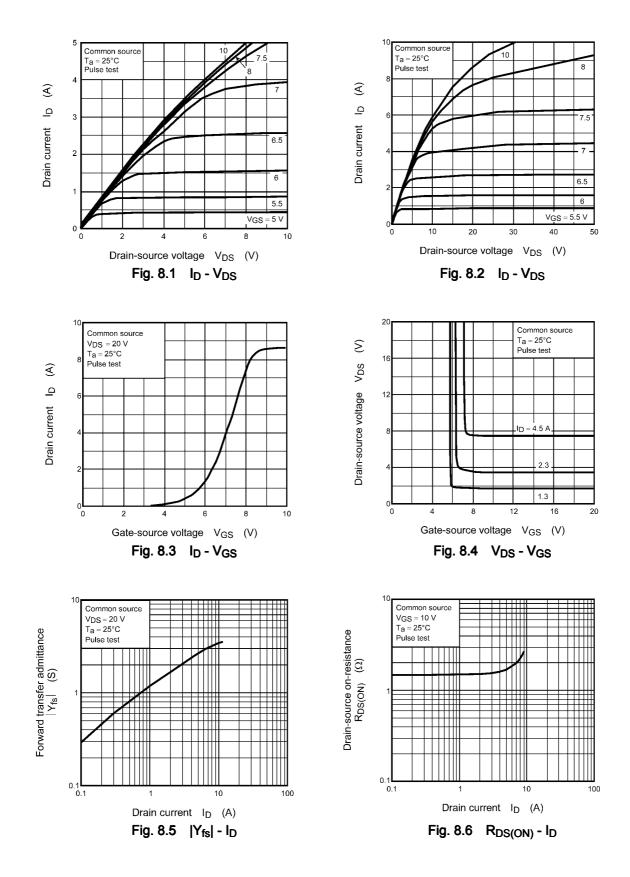
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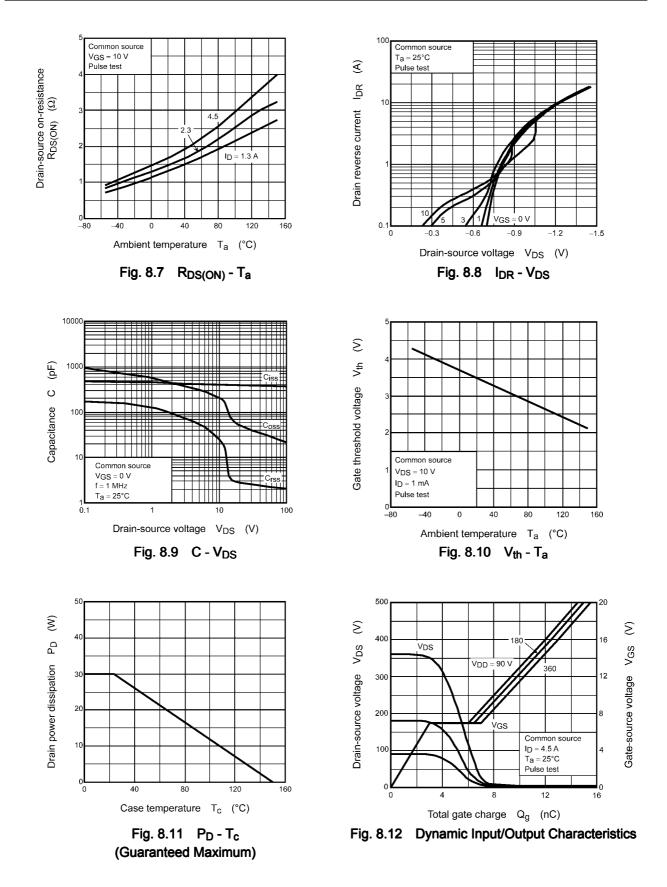
### 7. Marking (Note)

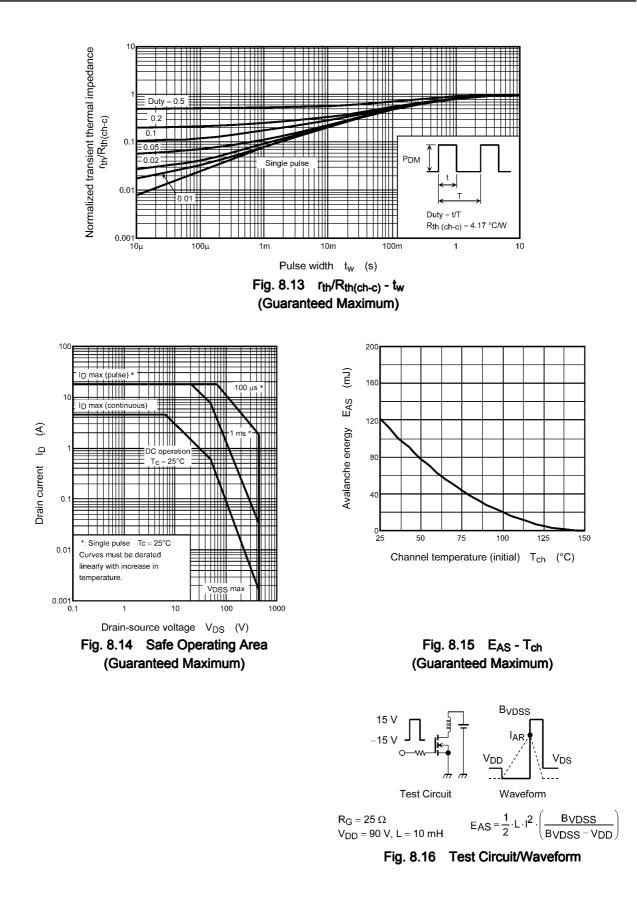


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### 8. Characteristics Curves (Note)





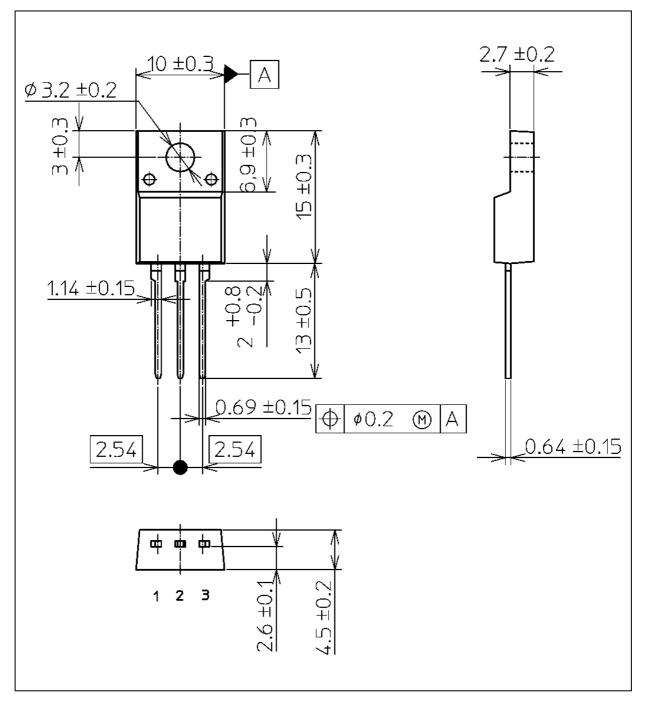


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

#### Package Dimensions

TK5A45DA

Unit: mm



Weight: 1.7 g (typ.)

Package Name(s)	
JEITA: SC-67	
TOSHIBA: 2-10U1S	
Nickname: TO-220SIS	

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